NSN 5961-01-094-1799

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-094-1799 **Inclosure Material:** Glass **Overall Length:** Between 0.100 inches and 0.170 inches **Terminal Length:** Between 0.975 inches and 1.500 inches **Overall Diameter:** Between 0.045 inches and 0.076 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 working peak reverse voltage, peak total value **Power Rating Per Characteristic:** 0.3 watts small-signal input power, common-collector of standard range **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Test Data Document:** 00724-20-00736 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: